

SF5G41A,SF5J41A

TOSHIBA THYRISTOR SILICON PLANAR TYPE

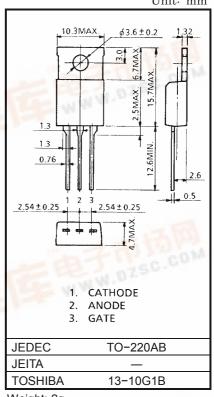
# SF5G41A,SF5J41A

### MEDIUM POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage : VDRM = 400, 600V Repetitive Peak Reverse Voltage
  - $: V_{RRM} = 400, 600V$
  - $I_{T}(AV) = 5A$
- Average On–State Current Gate Trigger Current
- : IGT = 15mA (MAX.)

#### **MAXIMUM RATINGS**

	2.54±0.25						
CHARACTERISTIC		SYMBOL	RATING	UNIT			
Repetitive Peak Off-State Voltage and Repetitive Peak Reverse Voltage	SF5G41A	V <sub>DRM</sub> V <sub>RRM</sub>	400	v	4		
	SF5J41A		600	V	1. CATHODE		
Non-Repetitive Peak Reverse Voltage (Non-Repetitive<5ms, Tj = 0~125°C)	SF5G41A	V <sub>RSM</sub>	500	V	2. ANODE 3. GATE		
	SF5J41A		720		JEDEC TO-220A	В	
Average On-State Current (Half Sine Waveform Tc = 91°C)		I <sub>T (AV)</sub>	5	А	JEITA — TOSHIBA 13-10G1	В	
R.M.S On-State Current		I <sub>T (RMS)</sub>	7.8	А	Weight: 2g		
Peak One Cycle Surge On-State Current (Non-Repetitive)		I <sub>TSM</sub>	80 (50Hz)	Α			
			88 (60Hz)				
I <sup>2</sup> t Limit Value		l <sup>2</sup> t	32	A <sup>2</sup> s			
Critical Rate of Rise of On-State Current		di / dt	100	A / µs			
Peak Gate Power Dissipation		P <sub>GM</sub>	5	W			
Average Gate Power Dissipation		P <sub>G (AV)</sub>	0.5	W			
Peak Forward Gate Voltage		V <sub>FGM</sub>	10	V			
Peak Reverse Gate Voltage		V <sub>RGM</sub>	-5	V			
Peak Forward Gate Current		I <sub>GM</sub>	2	A			
Junction Temperature		Tj	-40~125	°C			
Storage Temperature Range		T <sub>stg</sub>	-40~125	°C			





Unit: mm

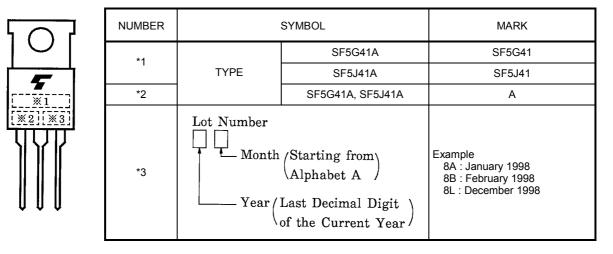
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#### ELECTRICAL CHARACTERISTICS (Ta = 25°C)

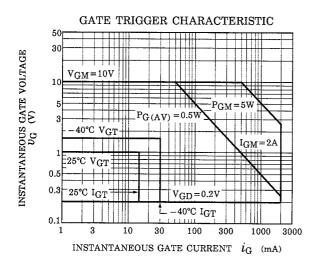
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
Repetitive Peak Off-State Current and Repetitive Peak Reverse Current	I <sub>DRM</sub> I <sub>RRM</sub>	V <sub>DRM</sub> = V <sub>RRM</sub> = Rated	_	10	μA
Peak On-State Voltage	V <sub>TM</sub>	I <sub>TM</sub> = 15A		1.6	V
Gate Trigger Voltage	V <sub>GT</sub>	V <sub>D</sub> = 6V, R <sub>I</sub> = 10Ω		1.0	V
Gate Trigger Current	I <sub>GT</sub>	VD - 0V, KL - 1022	_	15	mA
Gate Non-Trigger Voltage	V <sub>GD</sub>	V <sub>D</sub> = Rated × 2 / 3, Tc = 125°C	0.2	_	V
Critical Rate of Rise of Off-State Voltage	dv / dt	V <sub>DRM</sub> = Rated × 2 / 3, Tc = 125°C, Exponential Rise	100	_	V / µs
Holding Current	Ι <sub>Η</sub>	V <sub>D</sub> = 6V, I <sub>TM</sub> = 1A		40	mA
Latching Current	١L	V <sub>D</sub> = 6V, f = 50Hz, t <sub>gw</sub> = 50µs, i <sub>G</sub> = 30mA	_	60	mA
Thermal Resistance	R <sub>th (j−c)</sub>	Junction to Case	_	3	°C/W

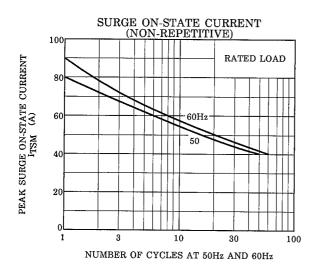
#### MARKING

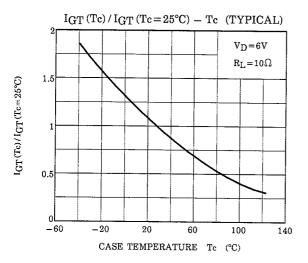


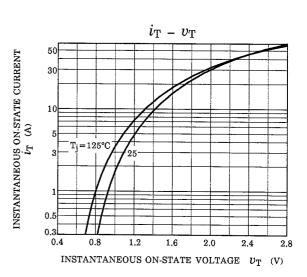
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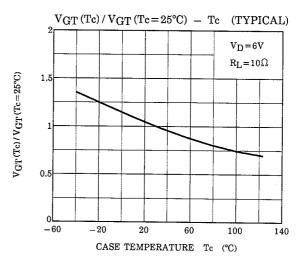
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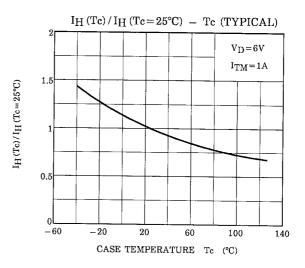






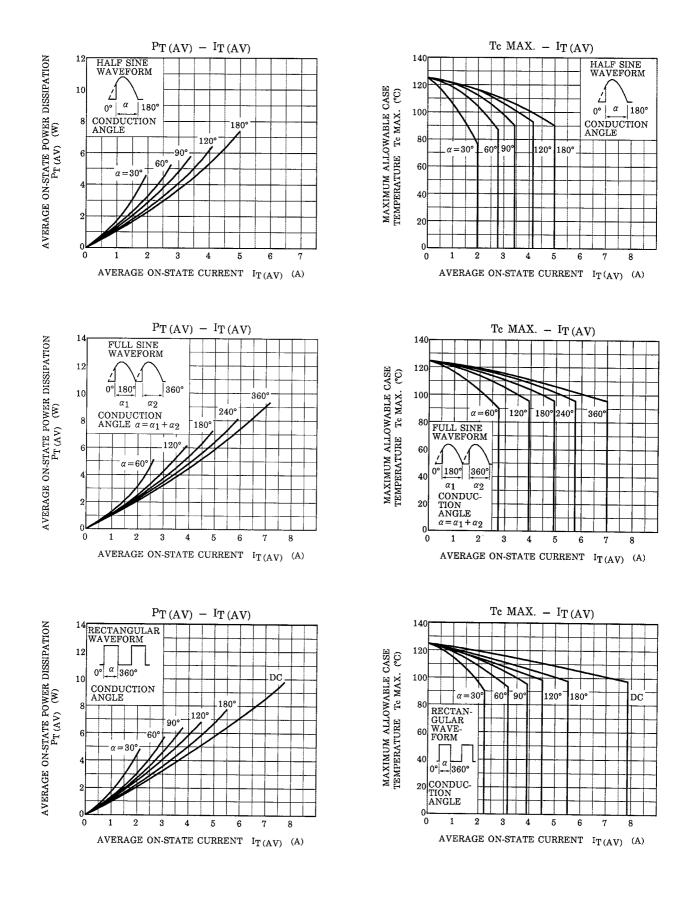






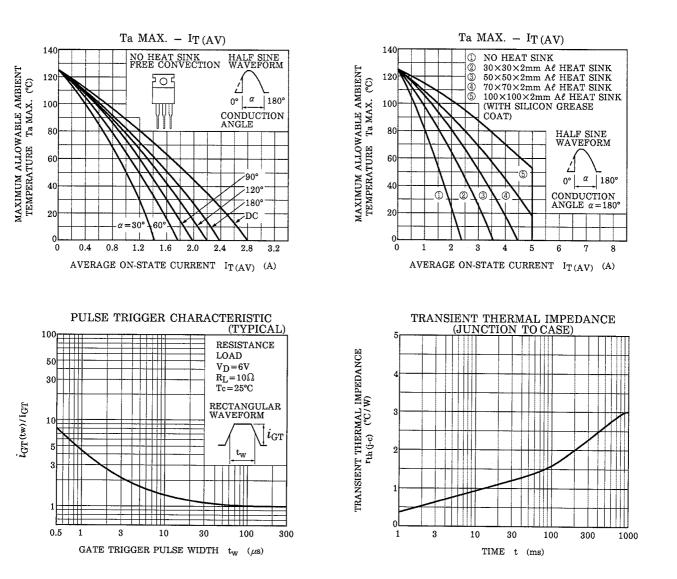
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